

(1983).

FIG. 1a

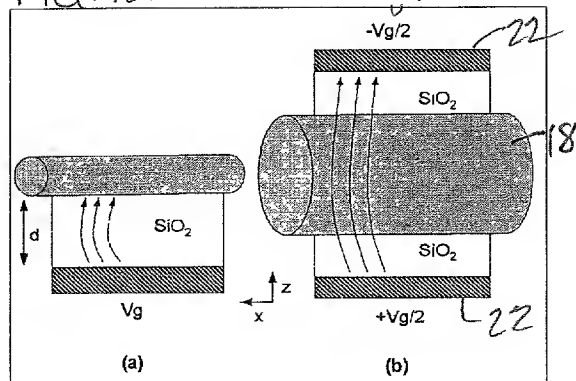


FIG. 1b

FIG. 3a

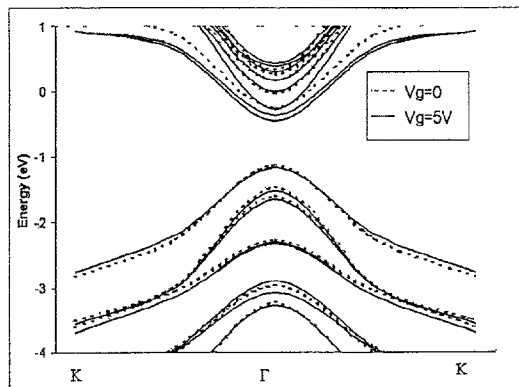


FIG. 3b

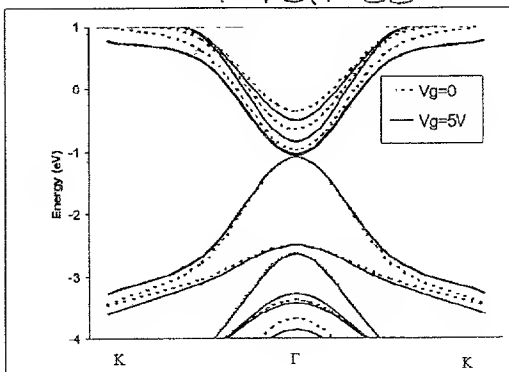


FIG. 2

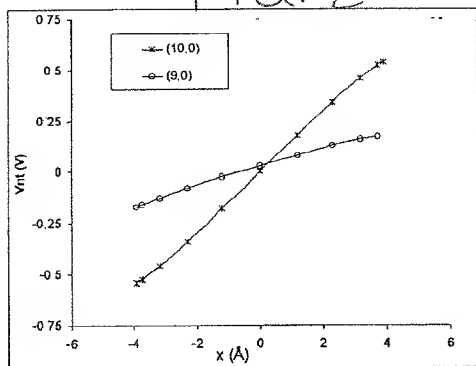
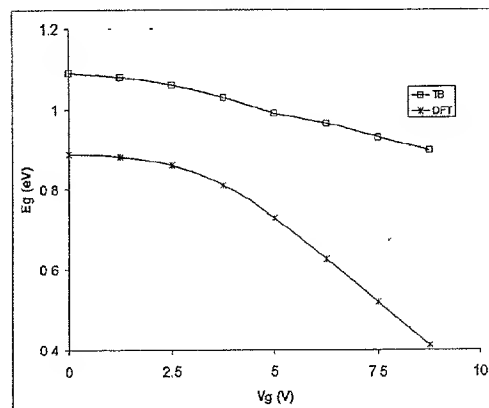


FIG. 4



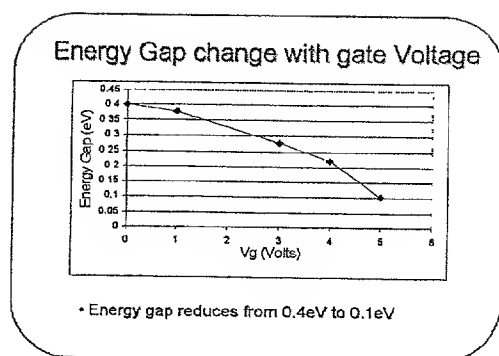


FIG.5

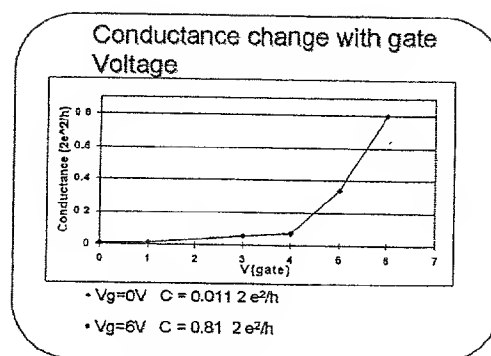


FIG.6

FIG. 7(a)

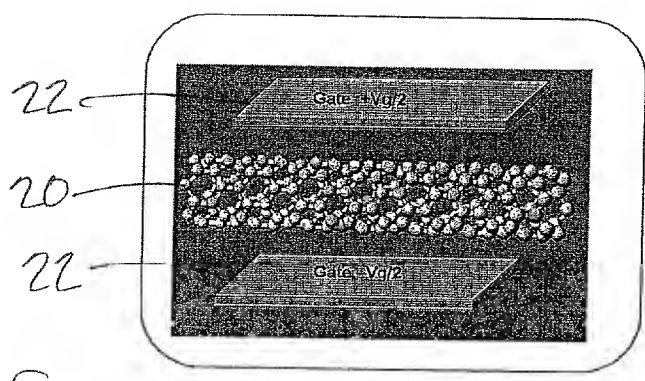


FIG. 7(a)

FIG. 7(b)

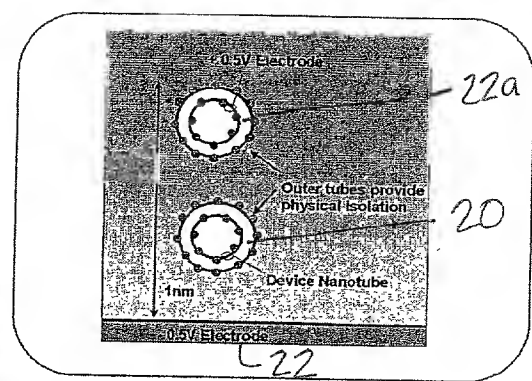
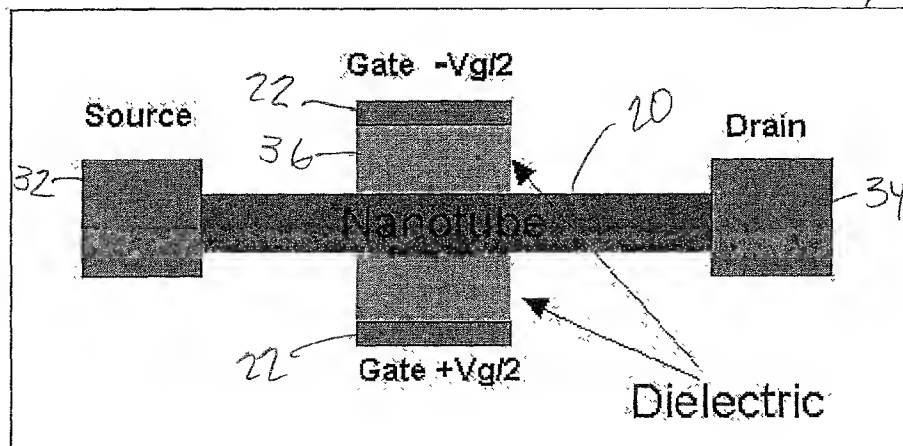


FIG. 8

1. Nanotube Field Effect switch 30



- The split-gate generates a potential gradient about the tube X-section.
- The energy-gap narrows as a result of the potential gradient.
- This causes a change (increase) in the source-drain conductance.
- The gate can be across part or all of the nanotube.

Variations on nanotube field effect switch 30''

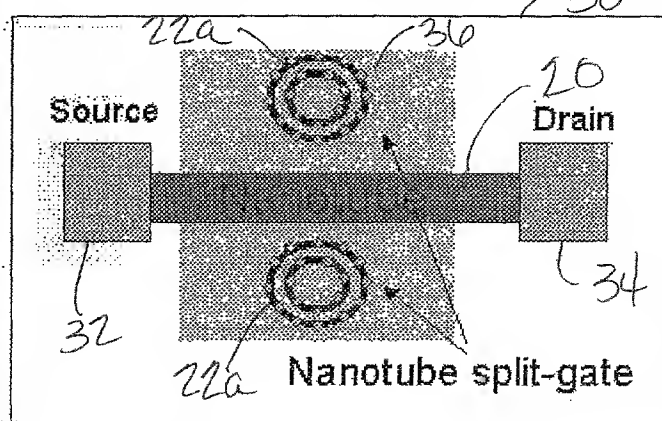


FIG. 9(a)

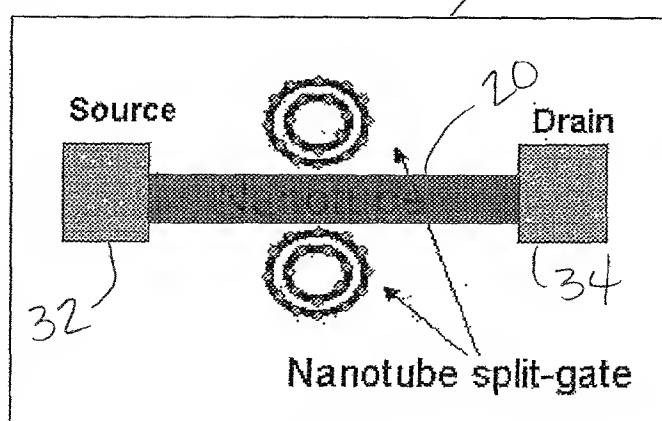


FIG. 9(b)

- A) Single or multi-wall tubes are used as gate electrodes. There is a dielectric (SiO_2 etc.) between the tubes.
- B) Same as (a) except there is no gate dielectric. The tubes form a crossing junction. There is capacitor action because there is only weak inter-tube conductance.

3. Modulated optical absorption

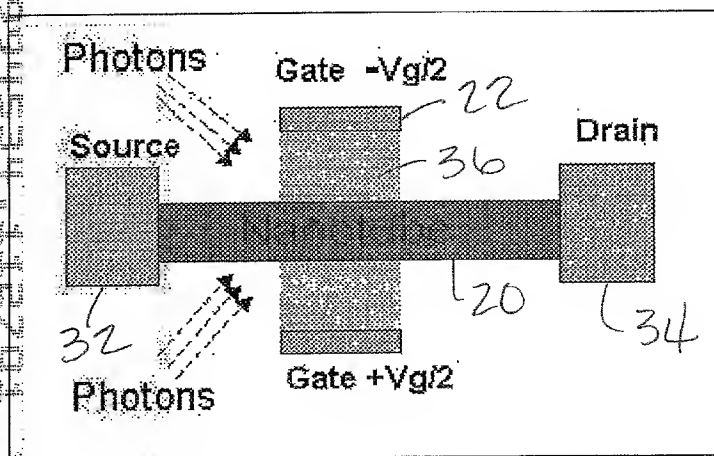


FIG. 10(a)

- The potential gradient narrows the energy gap and therefore shifts the optical absorption edge (illustrated in (b) for three different gate voltages)
- The energy gap and band-structure can be tuned to absorb specific photon energies. Electron-hole pairs are created when the photons are absorbed and results in a source-drain current. This is a typical photo-detector operation, except that it is tunable using energy gap modulation

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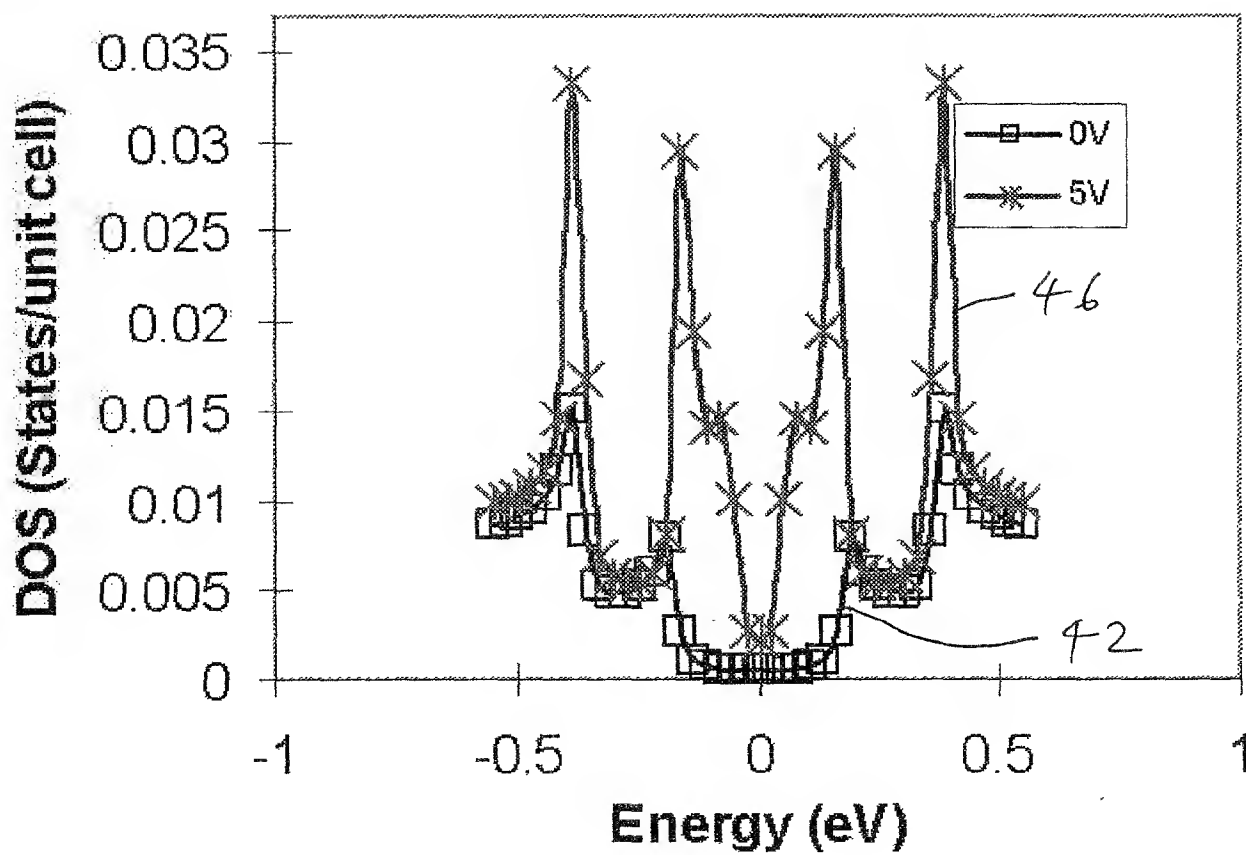
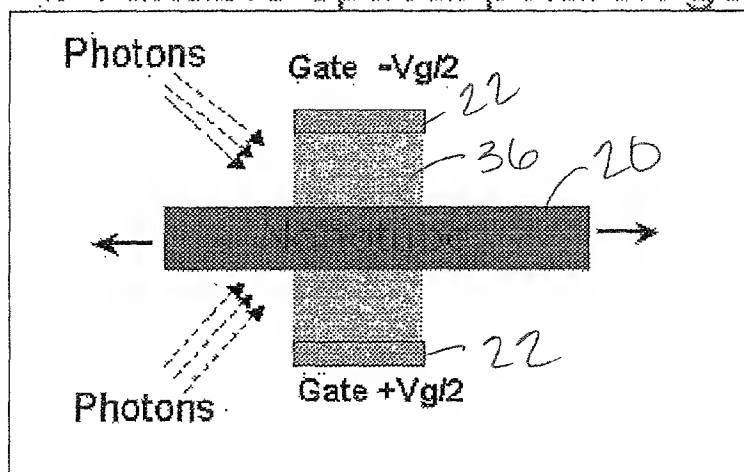


FIG. 106

FIG. 11

4. Tunable optical polaron generator



- Electron hole pairs are generated when the photons are absorbed.
- The electron hole pairs form polarons which cause the tube to deform mechanically (elongate or bend).
- Our claim is that we can control this process by modulating the amount of photon absorption.

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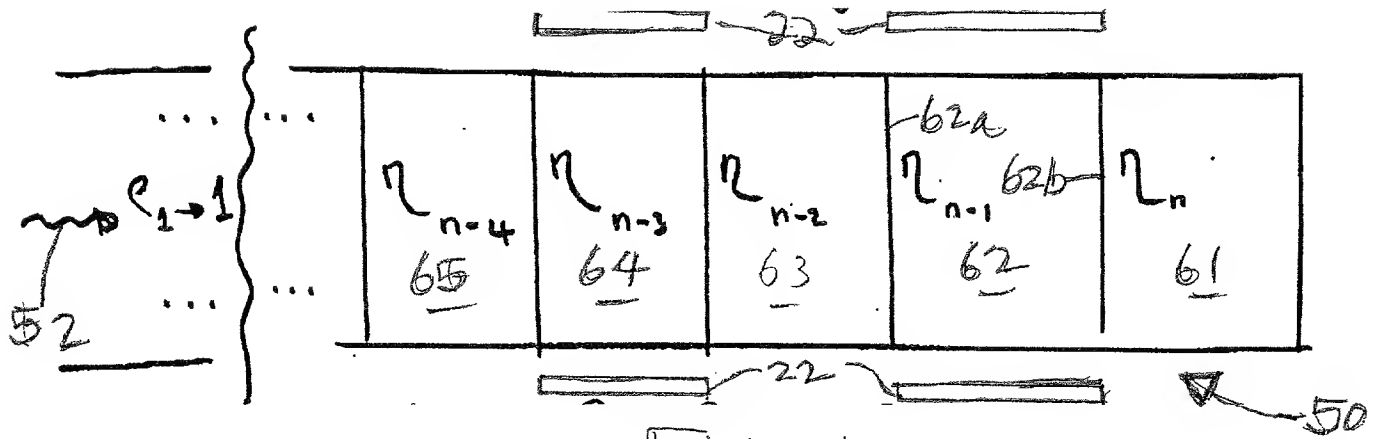
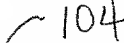


FIG. 12

100



36

22a

Δ 50

206

4104

22a

FIG. 14a

120

Verticle-emitting semiconductor laser (VCSEL)
Distributed Bragg reflectors on top and bottom

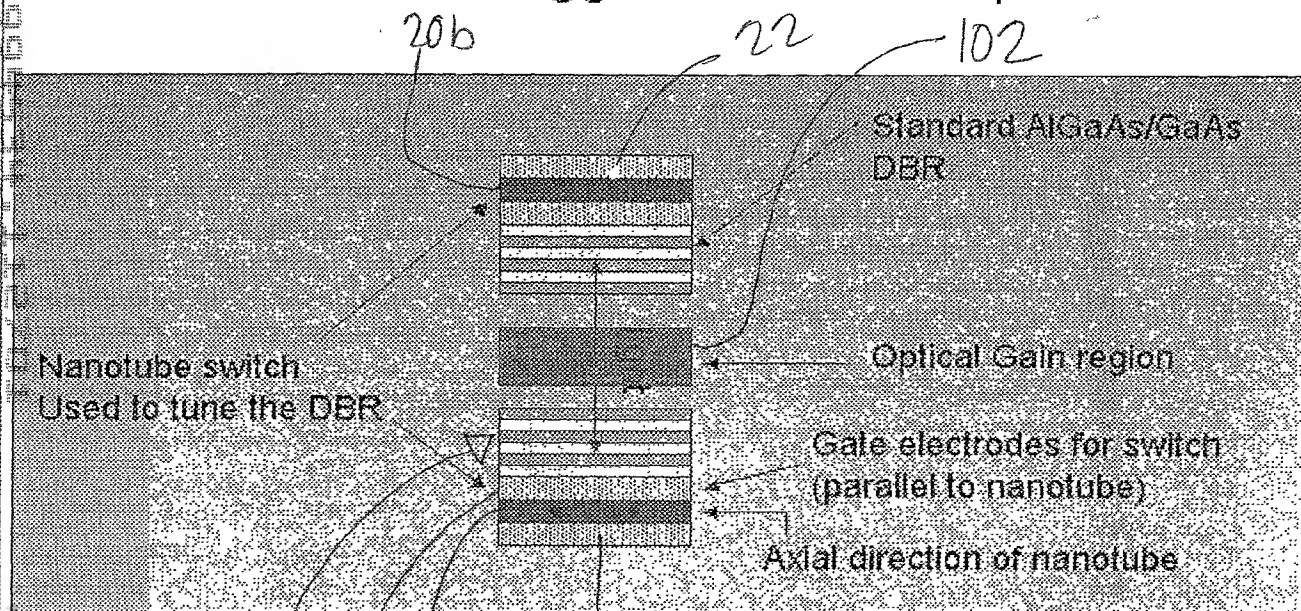
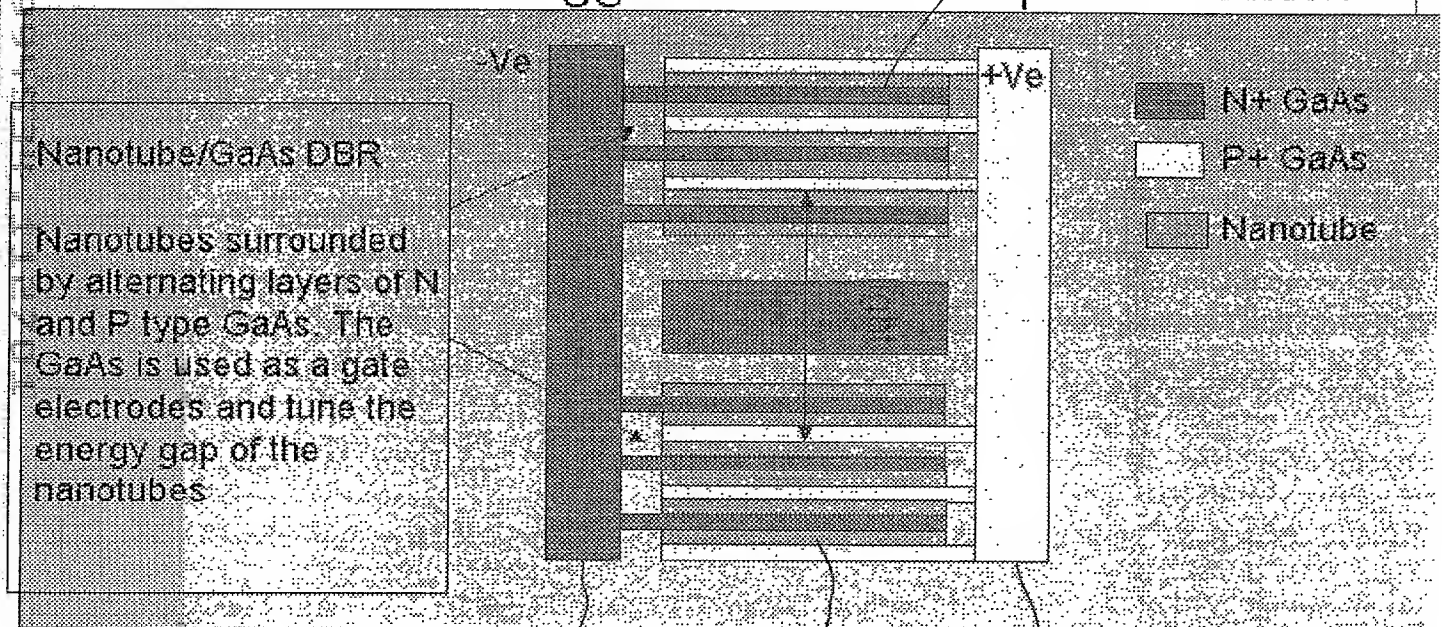


Fig. 14b

130

Verticle-emitting semiconductor laser (VCSEL)
Distributed Bragg reflectors on top and bottom

20

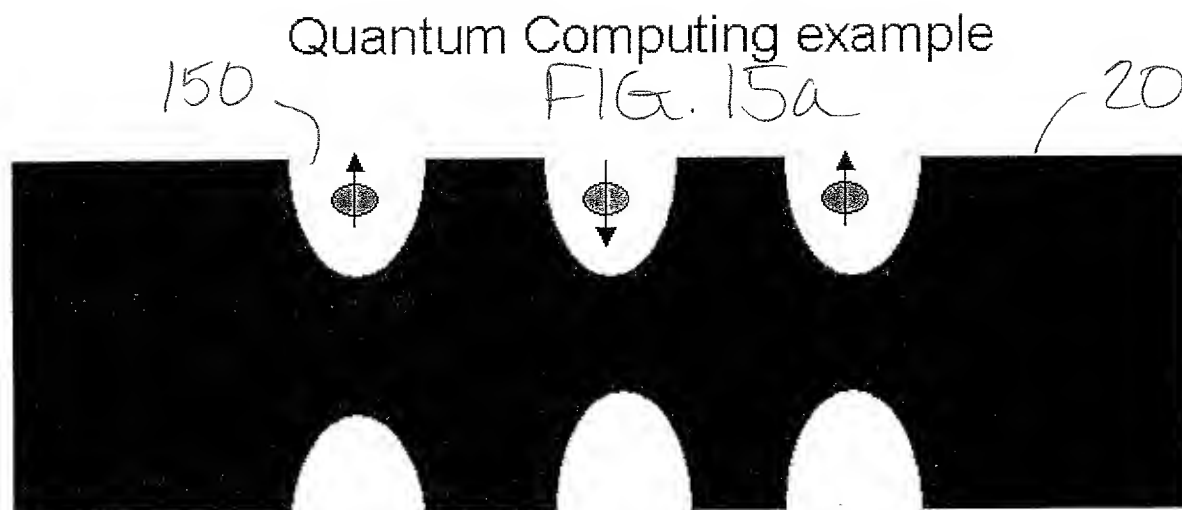


This is a neat way to bias many layers of nanotubes with an optically suitable gating material

134

20

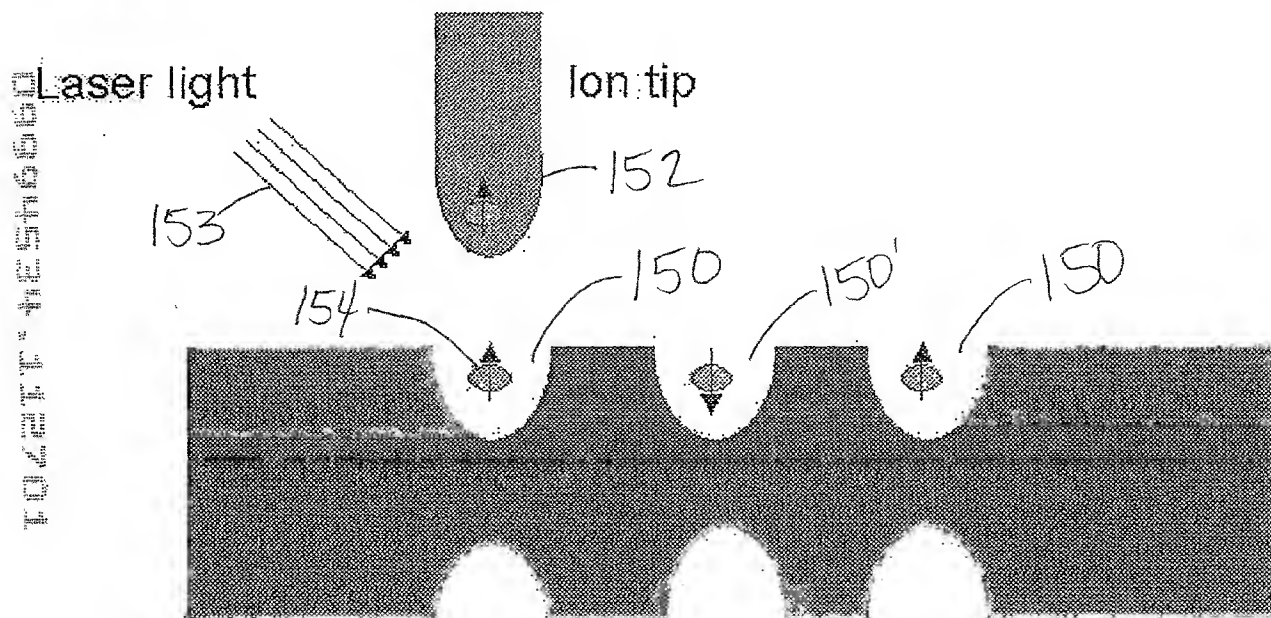
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- Multiple quantum wells are created along the tube.
- In this example the spins in the outer wells are used to manipulate the spins in the center well.
- The wells used to store confine electrons in well defined spin states i.e. \uparrow Or \downarrow

FIG. 15b

Quantum Computing example: Reading and Writing



- Using a laser pulse in conjunction with an ion tip, the electron spin state from the tip is placed onto the Q-well
- When the laser is off the state in the Q-well is read by the ion tip.